μESD3.3ST5G SERIES

ESD Protection Diodes

In Ultra Small SOD-723 Package

The μESD Series is designed to protect voltage sensitive components from ESD. Excellent clamping capability, low leakage, and fast response time provide best in class protection on designs that are exposed to ESD. Because of its small size, it is suited for use in cellular phones, MP3 players, digital cameras and many other portable applications where board space comes at a premium.

Specification Features:

• Small Body Outline Dimensions: 0.055" x 0.024" (1.40 mm x 0.60 mm)

Low Body Height: 0.020" (0.5 mm)
Stand-off Voltage: 3.3 V - 12 V

• Low Leakage

• Response Time is Typically < 1 ns

• ESD Rating of Class 3 (> 16 kV) per Human Body Model

IEC61000-4-2 Level 4 ESD Protection
IEC61000-4-4 Level 4 EFT Protection

• These are Pb-Free Devices

Mechanical Characteristics:

CASE: Void-free, transfer-molded, thermosetting plastic

Epoxy Meets UL 94 V-0

LEAD FINISH: 100% Matte Sn (Tin)

MOUNTING POSITION: Any

QUALIFIED MAX REFLOW TEMPERATURE: 260°C

Device Meets MSL 1 Requirements

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
IEC 61000-4-2 (ESD) Air Contact		±30 ±30	kV
IEC 61000-4-4 (EFT)		40	Α
ESD Voltage Per Human Body Model Per Machine Model		16 400	kV V
Total Power Dissipation on FR-5 Board (Note 1) @ T _A = 25°C	P _D	150	mW
Junction and Storage Temperature Range	T _J , T _{stg}	-55 to +150	°C
Lead Solder Temperature - Maximum (10 Second Duration)	TL	260	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. $FR-5 = 1.0 \times 0.75 \times 0.62$ in.



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PIN 1. CATHODE 2. ANODE



SOD-723 CASE 509AA





XX = Specific Device Code

M = Date Code ■ = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
μESDxxST5G	SOD-723 (Pb-Free)	8000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

DEVICE MARKING INFORMATION

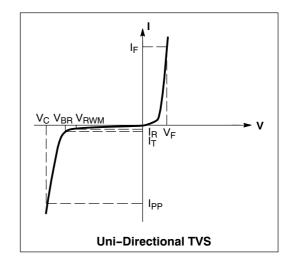
See specific marking information in the device marking column of the table on page 2 of this data sheet.

μESD3.3ST5G SERIES

ELECTRICAL CHARACTERISTICS

(T_A = 25°C unless otherwise noted)

	<u> </u>
Symbol	Parameter
I _{PP}	Maximum Reverse Peak Pulse Current
V _C	Clamping Voltage @ IPP
V_{RWM}	Working Peak Reverse Voltage
I _R	Maximum Reverse Leakage Current @ V _{RWM}
V_{BR}	Breakdown Voltage @ I _T
Ι _Τ	Test Current
I _F	Forward Current
V_{F}	Forward Voltage @ I _F
P _{pk}	Peak Power Dissipation
С	Max. Capacitance @V _R = 0 and f = 1 MHz



ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted, $V_F = 1.1$ V Max. @ $I_F = 10$ mA for all types)

	Device	V _{RWM} (V)	I _R (μΑ) @ V _{RWM}	V _{BR} (V) @ I _T (Note 2)	I _T	V _C (V) @ Max I _{PP} †	I _{PP} (A) [†]	P _{pk} (W) [†]	C (pF)
Device*	Marking	Max	Max	Min	mA	Max	Max	Max	Тур
μESD3.3ST5G	E0	3.3	2.5	5.0	1.0	10.9	10.4	113	80
μESD5.0ST5G	E2	5.0	1.0	6.2	1.0	13.3	8.8	117	65
μESD12ST5G	E3	12	1.0	13.5	1.0	23.7	5.4	128	30

^{*}Other voltages available upon request.

[†]Surge current waveform per Figure 1.
2. V_{BR} is measured with a pulse test current I_T at an ambient temperature of 25°C.

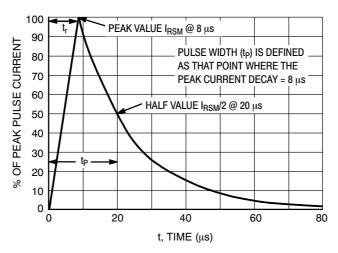


Figure 1. 8 x 20 µs Pulse Waveform

μESD3.3ST5G SERIES

TYPICAL CHARACTERISTICS

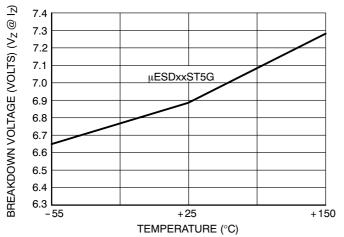


Figure 2. Typical Breakdown Voltage versus Temperature

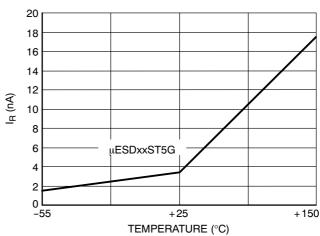


Figure 3. Typical Leakage Current versus Temperature

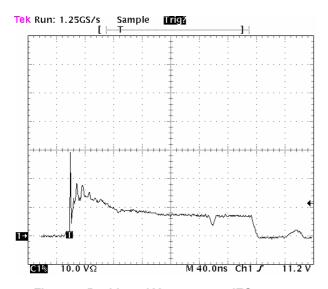


Figure 4. Positive 8 kV contact per IEC 6100-4-2 - μESD5.0ST5G

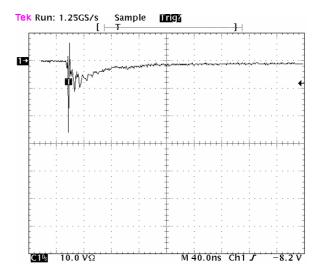


Figure 5. Negative 8 kV contact per IEC 61000-4-2 $- \mu$ ESD5.0ST5G





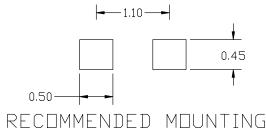
SOD-723, 2-LEAD, 1.00x0.60x0.52 CASE 509AA ISSUE A

DATE 01 FEB 2024

NOTES:

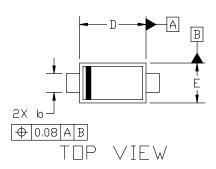
- DIMENSIONSING AND TOLERANCING PER ASME Y14.5M, 2018.
- 2. CONTROLLING DIMENSIONS: MILLIMETER.
- 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

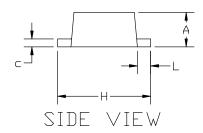
MIG	MILLIMETERS			
ויונע	MIN. NOM.		MAX.	
А	0.49	0.52	0.55	
b	0.25	0.28	0.32	
С	0.08	0.12	0.15	
D	0.95	1.00	1.05	
E	0.55	0.60	0.65	
Н	1.35	1.40	1.45	
L	0.15	0.20	0.25	



*For additional formation on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

FUUTERINT





GENERIC MARKING DIAGRAM*



XX = Specific Device Code M = Date Code

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DESCRIPTION:	SOD-723, 2-LEAD, 1.00x0.60x0.52		PAGE 1 OF 1	

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^{*}This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

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